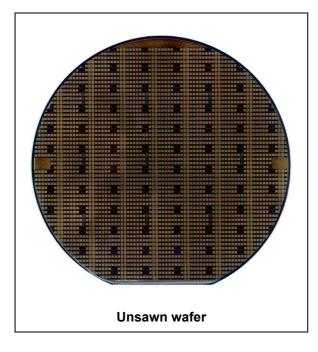


#### Micropower dual CMOS voltage comparator: unsawn wafer

Datasheet - production data



#### **Description**

The JTS393 is a micro power CMOS dual voltage comparator with extremely low consumption of 9  $\mu$ A typical per comparator (20 times less than the dual bipolar LM393 device). Similar performance is offered by the dual micropower TS3702 (or JTS3702 in wafer version) with a push-pull CMOS output. Thus, response times remain similar to the LM393.

#### **Features**

- Extremely low supply current: typically 9 µA per comparator
- Wide single supply range: 2.7 V to 16 V or dual supplies (±1.35 V to ±8 V)
- Extremely low input bias current: 1 pA typical
- Extremely low input offset currents: 1 pA typical
- Input common-mode voltage range includes ground
- High input impedance:  $10^{12} \Omega$  typical
- Fast response time: 2.5 µs typical for 5 mV overdrive
- Functionally compatible with bipolar LM393

#### **Related products**

• See TS393 for plastic packaged version

Contents JTS393

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#### Schematic diagram and pad configuration 1

Output

Figure 1. Schematic diagram (for one channel of JTS393)



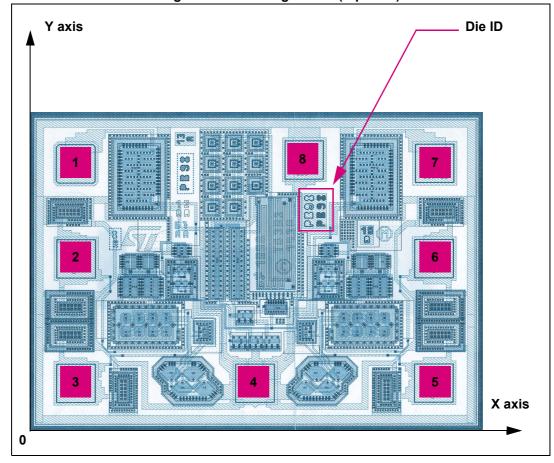




Table 1. Pad coordinates (pad placement origin is the lower left corner of the die)

Pad number	Ded description	Center pad coordinates		
Pad number	Pad description	X (μm)	Υ (μm)	
1	Output 1	165	870.3	
2	Inverting input 1	165	575.3	
3	Non-inverting input 1	165	140.3	
4	Vcc-	695	140.3	
5	Non-inverting input 2	1225	140.3	
6	Inverting input 2	1225	575.3	
7	Output 2	1225	870.3	
8	Vcc+	835	870.3	

Wafer dimension: 6 inches.

Die size without scribe line:

• X = 1326.0 µm

• Y = 926.0 µm

Scribe line: 60 µm

Bond pad opening 109 x 109 µm

## 2 Absolute maximum ratings and operating conditions

Table 2. Absolute maximum ratings (AMR)

Symbol	Parameter	Value	Unit	
V <sub>cc</sub> +	Supply voltage <sup>(1)</sup>	18		
V <sub>id</sub>	Differential input voltage <sup>(2)</sup>	±18	V	
V <sub>i</sub>	Input voltage <sup>(3)</sup>	18	V	
V <sub>o</sub>	Output voltage	18		
I <sub>o</sub>	Output current	20	mA	
I <sub>F</sub>	Forward current in ESD protection diodes on input <sup>(4)</sup>	50	ША	
T <sub>J</sub>	Maximum junction temperature	150	°C	
$T_{stg}$	Storage temperature range	-65 to +150		
ESD	HBM: human body model <sup>(5)</sup>	500	V	
LOD	MM: machine model <sup>(6)</sup>	200	V	

- 1. All voltage values, except differential voltage, are with respect to network ground terminal.
- 2. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
- Excursions of input voltages may exceed the power supply level. As long as the common-mode voltage
  [Vicm = (Vin+ + Vin-)/2] remains within the specified range, the comparator provides a stable output state.
  However, the maximum current through the ESD diodes (IF) of the input stage must strictly be observed.
- 4. Guaranteed by design.
- 5. Human body model: 100 pF discharged through a 1.5  $k\Omega$  resistor between two pins of the device, done for all couples of pin combinations with other pins floating.
- Machine model: a 200 pF cap is charged to the specified voltage, then discharged directly between two
  pins of the device with no external series resistor (internal resistor < 5 Ω), done for all couples of pin
  combinations with other pins floating.</li>

**Table 3. Operating conditions** 

Symbol	Parameter	Value	Unit
V <sub>cc</sub> +	Supply voltage	2.7 to 16	
V <sub>icm</sub>	Common mode input voltage range $T_{min}$ . $\leq T_{amb} \leq T_{max}$	0 to V <sub>cc</sub> <sup>+</sup> -1.2 0 to V <sub>cc</sub> <sup>+</sup> -1.5	V
$T_{oper}$	Operating free-air temperature range - JTS393C	0 to +70	°C



Electrical characteristics JTS393

### 3 Electrical characteristics

Table 4. Electrical characteristics at  $V_{CC+}$  = 3 V,  $V_{CC-}$  = 0 V, T = 25 °C (unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
$V_{io}$	Input offset voltage <sup>(1)</sup>	$V_{ic} = 1.5 \text{ V}$ $T_{min} \leq T_{amb} \leq T_{max}$			5 6.5	mV	
l <sub>io</sub>	Input offset current <sup>(2)</sup>	$V_{ic}$ = 1.5 V $T_{min}$ . $\leq T_{amb} \leq T_{max}$ .		1	300	5Λ	
l <sub>ib</sub>	Input bias current <sup>(2)</sup>	$V_{ic} = 1.5 \text{ V}$ $T_{min} \leq T_{amb} \leq T_{max}$		1	600	рA	
CMR	Common-mode rejection ratio	V <sub>ic</sub> = V <sub>icm min.</sub>		70		40	
SVR	Supply voltage rejection ratio	$V_{cc}^{+}$ = 3 V to 5 V		70		dB	
I <sub>OH</sub>	High level output current	$V_{id} = 1 \text{ V}, V_{OH} = 3 \text{ V}$ $T_{min.} \leq T_{amb} \leq T_{max.}$		2	40 1000	nA	
V <sub>OL</sub>	Low level output voltage	$V_{id}$ = -1 V, $I_{OL}$ = 6 mA $T_{min}$ . $\leq T_{amb} \leq T_{max}$ .		400	550 800	mV	
I <sub>cc</sub>	Supply current (each comparator)	No load - outputs low $T_{min}$ . $\leq T_{amb} \leq T_{max}$ .		9	20 25	μΑ	
t <sub>PLH</sub>	Response time low to high	$V_{ic}$ = 0 V, f = 10 kHz, $R_L$ = 5.1 k $\Omega$ C <sub>L</sub> = 50 pF, Overdrive = 5 mV TTL input		1.5 0.7			
t <sub>PHL</sub>	Response time high to low	$V_{ic}$ = 0 V, f = 10 kHz, $R_L$ = 5.1 k $\Omega$ C <sub>L</sub> = 50 pF, Overdrive = 5 mV TTL input		2.5 0.08		μs	

<sup>1.</sup> The specified offset voltage is the maximum value required to drive the output up to  $2.5\,\mathrm{V}$  or down to  $0.3\,\mathrm{V}$ .

<sup>2.</sup> Maximum values including unavoidable inaccuracies of the industrial test.

Table 5. Electrical characteristics at  $V_{CC+}$  = 5 V,  $V_{CC-}$  = 0 V, T = 25 °C (unless otherwise specified)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
$V_{io}$	Input offset voltage <sup>(1)</sup>	$V_{ic} = 2.5 \text{ V}, V_{cc}^{+} = 5 \text{ V to } 10 \text{ V}$ $T_{min}. \le T_{amb} \le T_{max}.$		1.4	5 6.5	mV
l <sub>io</sub>	Input offset current <sup>(2)</sup>	$V_{ic} = 2.5 \text{ V}$ $T_{min.} \leq T_{amb} \leq T_{max.}$		1	300	nΛ
l <sub>ib</sub>	Input bias current <sup>(2)</sup>	$V_{ic} = 2.5 \text{ V}$ $T_{min.} \leq T_{amb} \leq T_{max.}$		1	600	рA
CMR	Common-mode rejection ratio	V <sub>ic</sub> = 0 V		71		dB
SVR	Supply voltage rejection ratio	$V_{cc}^{+}$ = +5 V to +10 V		80		uБ
I <sub>OH</sub>	High level output current	$V_{id} = 1 \text{ V}, V_{OH} = 5 \text{ V}$ $T_{min}. \le T_{amb} \le T_{max}.$		2	40 1000	nA
V <sub>OL</sub>	Low level output voltage	$V_{id}$ = -1 V, $I_{OL}$ = 6 mA $T_{min}$ . $\leq T_{amb} \leq T_{max}$ .		260	400 650	mV
I <sub>cc</sub>	Supply current (each comparator)	No load - outputs low $T_{min}$ . $\leq T_{amb} \leq T_{max}$ .		10	20 25	μΑ
t <sub>PLH</sub>	Response time low to high	$V_{lc} = 0 \text{ V},  \text{f} = 1 \text{ 0kHz}, \\ R_{L} = 5.1  \text{k}\Omega   \text{C}_{L} = 50 \text{ pF}, \\ \text{Overdrive} = 5 \text{ mV} \\ \text{Overdrive} = 10 \text{ mV} \\ \text{Overdrive} = 20 \text{ mV} \\ \text{Overdrive} = 40 \text{ mV} \\ \text{TTL input}$		1.5 1.2 1.0 0.8 0.7		
t <sub>PHL</sub>	Response time high to low	$V_{ic}$ = 0 V, f = 10 kHz, $R_L$ = 5.1 k $\Omega$ C $_L$ = 50 pF, Overdrive = 5 mV Overdrive = 10 mV Overdrive = 20 mV Overdrive = 40 mV TTL input		2.5 1.9 1.2 0.8 0.08		μs
t <sub>f</sub>	Fall time	$f$ = 10 kHz, $C_L$ = 50 pF, $R_L$ = 5.1 kΩ, overdrive 50 mV		25		ns

<sup>1.</sup> The specified offset voltage is the maximum value required to drive the output up to  $4.5\,\mathrm{V}$  or down to  $0.3\,\mathrm{V}$ .

<sup>2.</sup> Maximum values including unavoidable inaccuracies of the industrial test.

Packing description JTS393

## 4 Packing description

Collective packing is used as STMicroelectronics qualified system for shipment of finished wafers.

The following parts of the collective packing are used in the clean room (see *Figure 3* for detailed view):

- Canister (composed of a base and a cover, maximum content is 25 wafers)
- Pink foam discs (lodged below and over the stack, minimum content is 2 discs)
- White interleaves (separators between wafers, maximum content is 26 or more for best fit).
- CMB bag (to protect canister under moderate vacuum)

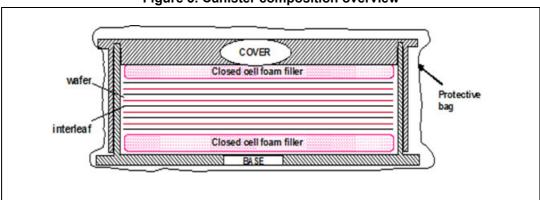
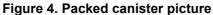


Figure 3. Canister composition overview





# 5 Ordering information

Table 6. Order codes

Order code	Temperature range	Package	Packaging
JTS393C-1AA5	0 to +70 °C	Unsawn wafer	Collective packing

## 6 Revision history

**Table 7. Document revision history** 

Date	Revision	Changes
18-Dec-2013	1	Initial release

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